

SANYO Semiconductors DATA SHEET

DLM10 — Silicon Diffused Junction Type 1.0A Ultrahigh-Speed Rectifier

Applications

· Switching regulators, high-frequency rectification.

Features

· Fast reverse recovery time and small switching loss.

Reverse voltage: VRM=200 to 400V.
Average rectified current: IO=1.0A.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	DLM10C DLM10E		Unit
Peak Reverse Voltage	V _{RM}		200	400	V
Average Rectified Current	lo	50Hz, resistive load, no fin, Ta=57°C resistive load (L=8mm, print land 10×10mm)	1	Α	
Surge Forward Current	IFSM	50Hz sine wave, 1cycle	30		А
Junction Temperature	Tj		150		°C
Storage Temperature	Tstg		-40 to +150		°C

Electrical Characteristics [DLM10C] at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Forward Voltage	VF	IF=1.0A			0.98	٧
Reverse Current	IR	V _{RM} =200V			10	μΑ
Reverse Recovery Time	t _{rr}	I _{FM} =1A, -di/dt=50A/μs			35	ns
Thermal Resistance (Junction-Ambient)	Rth(j-a)	No heat sink, DLM10 only			115	°C/W

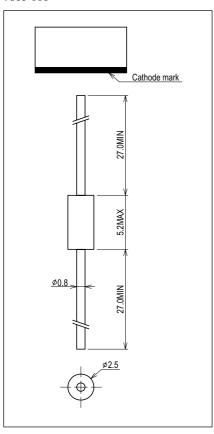
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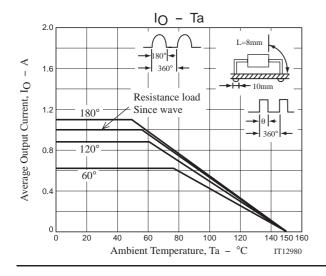
Electrical Characteristics [DLM10E] at Ta=25°C

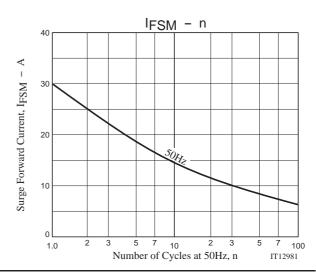
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Forward Voltage	٧F	IF=1.0A			1.25	V
Reverse Current	IR	V _{RM} =400V			20	μА
Reverse Recovery Time	trr	IFM=1A, -di/dt=50A/μs			30	ns
Thermal Resistance (Junction-Ambient)	Rth(j-a)	No heat sink, DLM10 only			115	°C/W

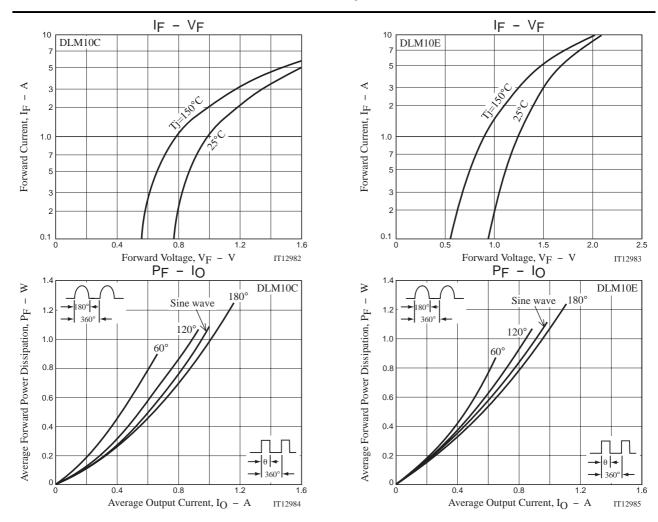
Package Dimensions

unit : mm (typ) 7811-001









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